#### CD4017B Decade Counter/Divider with 10 Decoded Outputs

#### CD4022B Divide-by-8 Counter/Divider with 8 Decoded Outputs

#### **Features**

- Wide supply voltage range: 3.0V to 15V
- High noise immunity: 0.45 VDD (typ.)
- Low power: Fan out of 2 driving 74L
- TTL compatibility or 1 driving 74LS
- Medium speed operation 5.0 MHz (typ.): with 10V VDD
- Low power: 10 μW (typ.)
- Fully static operation



### **Ordering Information**

DEVICE	Package Type	MARKING	Packing	Packing Qty
CD4017BPG	DIP-16	CD4017B	TUBE	1000pcs/box
CD4017BDRG	SOP-16	CD4017B	REEL	2500pcs/reel
CD4017BPWRG	TSSOP-16	CD4017B	REEL	2500pcs/reel
CD4022BPG	DIP-16	CD4022B	TUBE	1000pcs/box
CD4022BDRG	SOP-16	CD4022B	REEL	2500pcs/reel
CD4022BPWRG	TSSOP-16	CD4022B	REEL	2500pcs/reel



### **General Description**

The CD4017B is a 5-stage divide-by-10 Johnson counter with 10 decoded outputs and a carry out bit. The CD4022B is a 4-stage divide-by-8 Johnson counter with 8 decoded outputs and a carry-out bit. These counters are cleared to their zero count by a logical "1" on their reset line. These counters are advanced on the positive edge of the clock signal when the clock enable signal is in the logical "0" state.

The configuration of the CD4017B and CD4022B permits medium speed operation and assures a hazard free counting sequence. The 10/8 decoded outputs are normally in the logical "0" state and go to the logical "1" state only at their respective time slot. Each decoded output remains high for 1 full clock cycle.

The carry-out signal completes a full cycle for every 10/8 clock input cycles and is used as a ripple carry signal to any succeeding stages.

### Applications

- Automotive
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering



### **Connection Diagrams**



### Absolute Maximum Ratings (Notes 1 & 2)

Condition	Min	Max	UNITS
DC Supply Voltage (V <sub>DD</sub> )	-0.5	+18	V
Input Voltage (V <sub>IN</sub> )	-0.5	+0.5	V
Storage Temperature (Ts)	-65	150	°C
Power Dissipation (P <sub>D</sub> )			
Dual-In-Line	-	700	mW
Small Outline	-	500	mW
Lead Temperature (T <sub>L</sub> ) (Soldering, 10 seconds)	-	245	°C

Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.

### Recommended Operating Conditions (Note 2)

Condition	Min	Max	UNITS
DC Supply Voltage (V <sub>DD</sub> )	+3	+15	V
Input Voltage (V <sub>IN</sub> )	0 to \	/ <sub>DD</sub>	-
Operating Temperature Range (T <sub>A</sub> )	-40	+85	°C



# DC Electrical CharacteristicsCD4017B, CD4022B (Note 2)

			-4	D°C		+25°		+85	5°C	
Symbol	Parameter	Conditions	Min	Мах	Min	Тур	Max	Min	Max	Units
	Quiesent	V <sub>DD</sub> = 5V		20		0.5	20		150	mA
I <sub>DD</sub>	Quiescent	V <sub>DD</sub> = 10V		40		1.0	40		300	mA
	Device Current	V <sub>DD</sub> = 15V		80		5.0	80		600	mA
		ll <sub>o</sub> l < 1.0 μΑ								
	Low Level	V <sub>DD</sub> = 5V		0.05		0	0.05		0.05	V
V <sub>OL</sub>	Output Voltage	V <sub>DD</sub> = 10V		0.05		0	0.05		0.05	V
		V <sub>DD</sub> = 15V		0.05		0	0.05		0.05	V
		ll <sub>o</sub> l < 1.0 μΑ								
	High Level	V <sub>DD</sub> = 5V	4.95		4.95	5		4.95		V
V <sub>OH</sub>	Output Voltage	V <sub>DD</sub> = 10V	9.95		9.95	10		9.95		V
		V <sub>DD</sub> = 15V	14.95		14.95	15		14.95		V
		II₀I < 1.0 mA								
VIL	Low Level	$V_{DD}$ = 5V, $V_{O}$ = 0.5V or 4.5V		1.5			1.5		1.5	V
VIL	Input Voltage	$V_{DD}$ = 10V, $V_{O}$ = 1.0V or 9.0V		3.0			3.0		3.0	V
		$V_{DD}$ = 15V, $V_0$ = 1.5V or 13.5V		4.0			4.0		4.0	V
		II₀I < 1.0 mA								
VIH	High Level	$V_{DD}$ =5V, $V_{O}$ =0.5V or 4.5V	3.5		3.5			3.5		V
V IH	Input Voltage	$V_{DD}$ =10V, $V_{O}$ =1.0V or 9.0V	7.0		7.0			7.0		V
		V <sub>DD</sub> =15V, V <sub>O</sub> =1.5V or 13.5V	11.0		11.0			11.0		V
	Low Level Output	$V_{DD}$ = 5V, $V_{O}$ = 0.4V	0.52		0.44	0.88		0.36		mA
IOL	Current (Note 3)	$V_{DD}$ = 10V, $V_{O}$ = 0.5V	1.3		1.1	2.25		0.9		mA
		V <sub>DD</sub> = 15V, V <sub>O</sub> = 1.5V	3.6		3.0	8.8		2.4		mA
	High Level Output	V <sub>DD</sub> = 5V, V <sub>O</sub> = 4.6V	-0.2		-0.16	-0.36		-0.12		mA
Іон	Current (Note 3)	V <sub>DD</sub> = 10V, V <sub>O</sub> = 9.5V	-0.5		-0.4	-0.9		-0.3		mA
		V <sub>DD</sub> = 15V,V <sub>O</sub> = 13.5V	-1.4		-1.2	-3.5		-1.0		mA
I <sub>IN</sub>	Input Current	$V_{DD}$ = 15V, $V_{IN}$ = 0V		-0.3		<b>-10</b> -5	-0.3		-1.0	μA
UN UN		V <sub>DD</sub> =15V, V <sub>IN</sub> = 15V		0.3		10 <sup>-5</sup>	0.3		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: VSS e 0V unless otherwise specified.

Note 3:  $I_{\text{OL}}$  and  $I_{\text{OH}}$  are tested one output at a time

# **AC Electrical Characteristics\***

Symbol	Parameter	Cond	Min	Тур	Max	Units	
		CLOCK OPE	RATION				
	Dropogation Dalay	V <sub>DD</sub> :		415	800	ns	
	Propagation Delay	V <sub>DD</sub> =	=10V		160	320	ns
	Time Carry Out Line	V <sub>DD</sub> =	= 15V		130	250	ns
		VDD = 5V	)		240	480	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Carry Out Line	VDD = 10V	}C∟ = 15 pF		85	170	ns
		VDD = 15V	()		70	140	ns
		V <sub>DD</sub> :	= 5V		500	1000	ns
	Decode Out Lines	V <sub>DD</sub> =	= 10V		200	400	ns
		V <sub>DD</sub> =	= 15V		160	320	ns
		V <sub>DD</sub> :	= 5V		200	360	ns
	Transition Time Carry Out and	V <sub>DD</sub> =	= 10V		100	180	ns
	Decode Out Lines $t_{TLH}$	V <sub>DD</sub> =	= 15V		80	130	ns
ttlh, tthl		V <sub>DD</sub> :		100	200	ns	
	t <sub>THL</sub>	V <sub>DD</sub> =		50	100	ns	
		V <sub>DD</sub> =	= 15V		40	80	ns
		VDD = 5V)	Measured with	1.0	2		MHz
fCL	Maximum Clock Frequency	VDD = 10V VDD = 15V	Respect to Carry	2.5	5		MHz
		VDD - 13V/	Output Line	3.0	6		MHz
		V <sub>DD</sub> :	= 5V		125	250	Ns
twL, twн	Minimum Clock Pulse Width	V <sub>DD</sub> =	= 10V		45	90	Ns
		V <sub>DD</sub> =	= 15V		35	70	ns
		V <sub>DD</sub> :	= 5V			20	μs
t <sub>rCL</sub> , t <sub>fCL</sub>	Clock Rise and Fall Time	V <sub>DD</sub> =	= 10V			15	μs
		V <sub>DD</sub> =	=15V			5	μs
		V <sub>DD</sub> :	= 5V		120	240	Ns
ts∪	Minimum Clock Inhibit	V <sub>DD</sub> =	= 10V		40	80	Ns
	Data Setup Time	V <sub>DD</sub> =	= 15V		32	65	ns
CIN	Average Input Capacitance				5	7.5	pF

# **AC Electrical Characteristics**

$T_A = 25^{\circ}C$ , $C_L = 50$ pF, RL = 200k, trCL and tf CL = 20 ns, unless oth	herwise specified
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Symbol	Parameter	Conditions	Min	Тур	Мах	Units
		RESET OPERATION				
	Dreneration Dalow Time	V <sub>DD</sub> = 5V		415	800	ns
	Propagation Delay Time	V <sub>DD</sub> = 10V		160	320	ns
	Carry Out Line	V <sub>DD</sub> = 15V		130	250	ns
				240	480	ns
t <sub>PHL</sub> , t <sub>PLH</sub>	Carry Out Line	$\begin{array}{l} VDD = 5V \\ VDD = 10V \end{array} \right\} \qquad C_{L} = 15 \text{ pF}$		85	170	ns
		VDD = 15V		70	140	ns
		V <sub>DD</sub> = 5V		500	1000	ns
	Decode Out Lines	V <sub>DD</sub> = 10V		200	400	ns
		V <sub>DD</sub> = 15V		160	320	ns
	Minimum Reset	V <sub>DD</sub> = 5V		200	400	ns
tw		V <sub>DD</sub> = 10V		70	140	ns
	Pulse Width	V <sub>DD</sub> = 15V		55	110	ns
	Minimum Doost	V <sub>DD</sub> = 5V		75	150	ns
t <sub>REM</sub>	Minimum Reset	V <sub>DD</sub> = 10V		30	60	ns
	Removal Time	V <sub>DD</sub> = 15V		25	50	ns

\*AC Parameters are guaranteed by DC correlated testing.

### **Timing Diagrams**





#### Timing Diagrams (Continued)





# Logic Diagrams



Terminal No. 8 = GND Terminal No. 16 =  $V_{DD}$ 



Terminal No. 16 =  $V_{DD}$ Terminal No. 8 = GND



# **Physical Dimensions**

#### DIP-16





Dimensions In Millimeters(DIP-16)											
Symbol:	A	В	D	D1	E	L	L1	а	b	с	d
Min:	6.10	18.94	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54 BSC
Max:	6.68	19.56	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	2.04 030

SOP-16



Dimensions In Millimeters(SOP-16)										
Symbol:	А	A1	В	С	C1	D	Q	а	b	
Min:	1.35	0.05	9.80	5.80	3.80	0.40	0°	0.35	1.27 BSC	
Max:	1.55	0.20	10.0	6.20	4.00	0.80	8°	0.45	1.27 830	



# **Physical Dimensions**

#### TSSOP-16



Dimensions In Millimeters(TSSOP-16)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.00 030



# **Revision History**

DATE	REVISION	PAGE
2014-6-7	New	1-12
2023-9-8	Modify the package dimension diagram SSOP-16、Update encapsulation type、 Update Lead Temperature、Updated DIP-16 dimension、Add annotation for Maximum Ratings.	1、3、9、11



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